## NSN 5962-01-076-8401

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Body Length:	
0.440 inches	
Body Width:	
Between 0.248 inche	s and 0.325 inches
Body Height:	
0.085 inches	
Maximum Power Dis	sipation Rating:
910.0 milliwatts	
Operating Tempurat	ure Range:
-55.0/+125.0 degrees	celsius
Storage Tempuratur	e Range:
-65.0/+150.0 degrees	celsius
Features Provided:	
Hermetically sealed a	nd monolithic and positive outputs and w/storage and programmable and programmed and bipolar and 3-state output
and schottky and high	speed and expandable and w/buffered output and w/decoded output and w/enable and w/disable
Inclosure Material:	
Ceramic and glass	
Inclosure Configura	tion:
Flat pack	
Output Logic Form:	
Transistor-transistor	ogic
Input Circuit Pattern	:
6 input	
Terminal Surface Tr	eatment:
Solder	
Voltage Rating And	Type Per Characteristic:
5.5 volts power source	
Time Rating Per Cha	acteristic:
40.00 nanoseconds	propagation delay time, low to high level output and 84.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Typ	8:
Rom	
Memory Capacity:	
Unknown	
Test Data Document	
82577-932821 standa	ard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And	
16 flat leads	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	

Yes - demil/mli

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